

Features:

supported components:

BJT

JFET

E-IGBT

D-IGBT

E-MOS

D-MOS

resistors

coils

capacitors

diodes

auto shutdown

shows pin layout

Specifications:

dimensions: 137 x 60 x 30 (W x L x H)

resistance resolution: 0.1 Ohm (max. 50 MOhm)

capacitance range: 28 pF to 100 mF

inductance range: 0.01 mH to 20 H

standby current: 20 nA

power supply: 9 V battery

test current approx.: 20 mA

test speed: 2 seconds